



T1650 – 600 Series

TRIAC

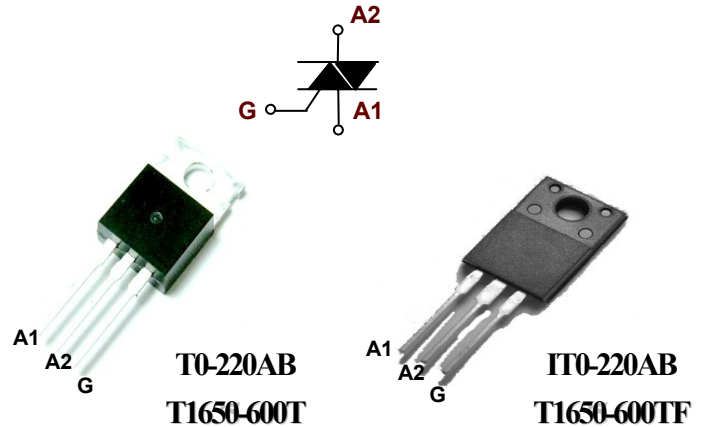
Main features

I_{GT} 50mA

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
V_{DRM}/V_{RRM}	600	V

Description

The T1635 series is suitable for general purpose AC switching. They can be used as an ON/OFF function in application such as static relays, heating regulation, induction motor starting circuits or for phase control operation in light dimmers, motor speed controllers,...



Absolute maximum ratings

Symbol	Parameter	Value	Unit	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	16	A	
I_{TSM}	Non repetitive surge on-state current (full sine wave , T_j initial=25°C)	F = 50Hz t = 20ms	160	A
		F = 60Hz t = 16.7ms	168	
I^2T	I^2T Value for fusing	tp = 10ms	144	A ² s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100ns$	F = 120Hz $T_j = 25^\circ C$	50	A/us
I_{GM}	Peak gate current	tp = 20us $T_j = 25^\circ C$	4	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 25^\circ C$	1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range		-40 to +150 -40 to +110	°C

Electrical characteristics ($T_j = 25^\circ C$, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value	Unit
I_{GT}	$V_D = 12V$ $R_L = 100 \text{ ohm}$	I – II - III	MAX.	50	mA
V_{GT}		I – II - III	MAX.	1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3k \text{ ohm}$ $T_j = 125^\circ C$	I – II - III	MIN.	0.2	V
I_H			MAX.	45	mA
I_L		I - III	MAX.	50	mA
		II	MAX.	60	
dV/dt (1)	$V_D = 67 \% V_{DRM}$ gate open	$T_j = 25^\circ C$	MIN.	500	V/us

Static characteristics

Symbol	Test conditions	Value	Unit
V_T (1)	$I_{TM} = 22.5A$ tp = 380 us $T_j = 25^\circ C$	MAX.	1.65
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$ $T_j = 25^\circ C$	MAX.	5

Note 1 : for both polarities of A2 referenced to A1

Figure 1: Maximum power dissipation versus RMS on-state current (full cycle)

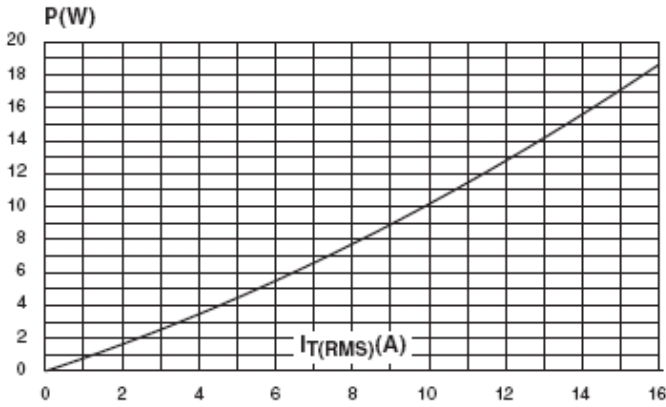


Figure 2: RMS on-state current versus case temperature (full cycle)

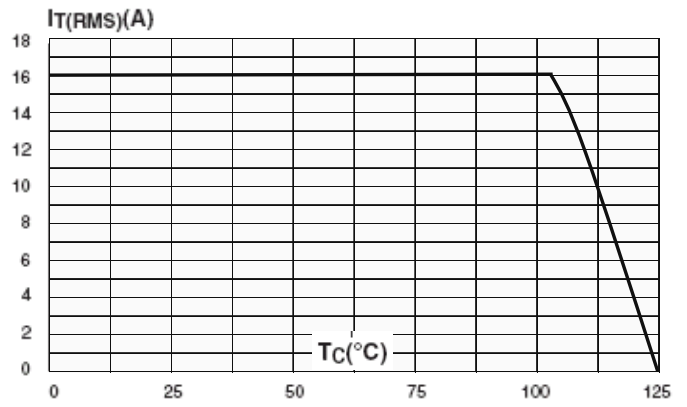


Figure 3: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35µm) (full cycle)

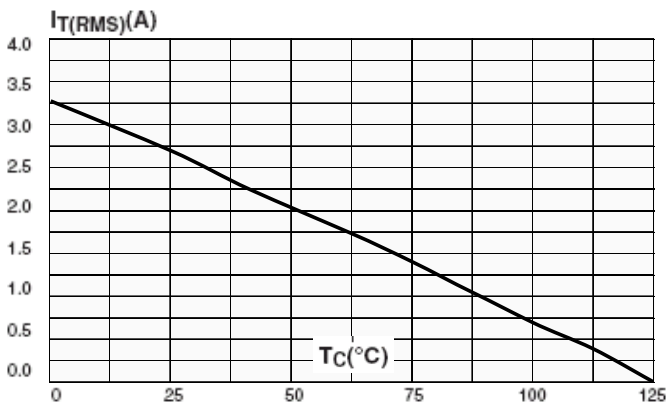


Figure 4: Relative variation of thermal impedance versus pulse duration

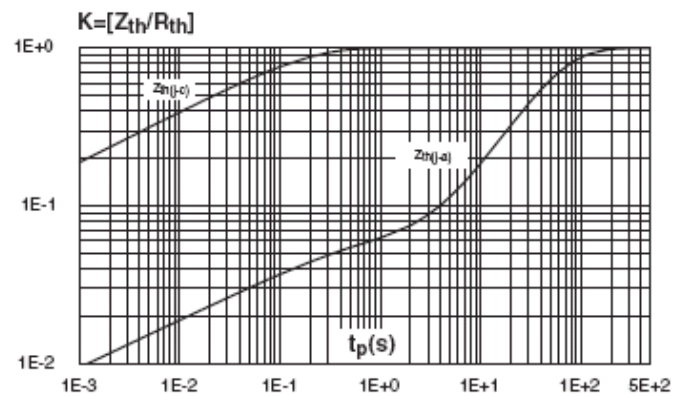


Figure 5: On-state characteristics (maximum values)

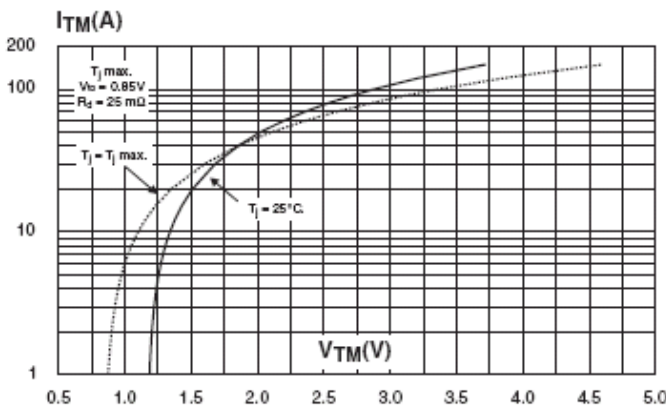


Figure 6: Surge peak on-state current versus number of cycles

